

**Product data sheet** 

## 1. General description

Planar passivated SCR with sensitive gate in a SOT223 (SC-73) surface mountable plastic package. These devices are intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

## 2. Features and benefits

- Sensitive gate
- Planar passivated for voltage ruggedness and reliability
- Direct triggering from low power drivers and logic ICs
- Surface mountable package

## 3. Applications

- Adapters
- Battery powered applications
- Industrial automation

## 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>RRM</sub>	repetitive peak reverse voltage			-	-	600	V
I <sub>T(AV)</sub>	average on-state current	half sine wave; T <sub>sp</sub> ≤ 112 °C; <u>Fig. 1</u>		-	-	0.6	A
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>sp</sub> ≤ 112 °C; <u>Fig. 2;</u> <u>Fig. 3</u>		-	-	1	A
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 10 ms; <u>Fig. 4; Fig. 5</u>		-	-	10	A
		half sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 8.3 ms		-	-	11	A
Tj	junction temperature		[1]	-	-	125	°C
Static characte	eristics						
I <sub>GT</sub>	gate trigger current	$V_D$ = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; Fig. 9		-	50	200	μA
Dynamic chara	acteristics				-		-
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 402 V; T <sub>j</sub> = 125 °C; R <sub>GK</sub> = 100 Ω; ( $V_{DM}$ = 67% of $V_{DRM}$ ); exponential waveform; Fig. 14		-	50	-	V/µs

[1] Operation above 110°C may require the use of a gate to cathode resistor of  $1k\Omega$  or less.

## 5. Pinning information

Table 2. F	Pinning inf	formation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	4	А <del>- Д </del> К
2	А	anode		G sym037
3	G	gate		symosi
4	mb	mb; connected to anode	⊟1 ⊟2 ⊟3 SC-73 (SOT223)	

## 6. Ordering informati

Table 3. Ordering information								
Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date		
BT148W-600R	SOT223	BT148W-600R, 115	Reel	1000	SOT223	16-Mar-2006		

### Marking codes

Type number	Marking codes			
	Assembly factory: L	Assembly factory: d		
BT148W-600R	JLxxx 60 BT148W	Jdxxx 60 BT148W		

## 7. Limiting values

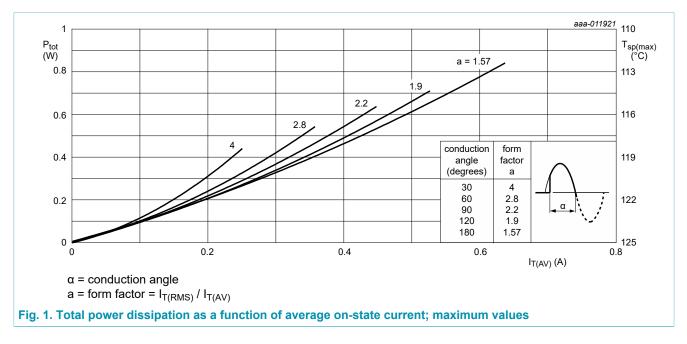
#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DRM</sub>	repetitive peak off-state voltage		[1]	-	600	V
V <sub>RRM</sub>	repetitive peak reverse voltage			-	600	V
I <sub>T(AV)</sub>	average on-state current	half sine wave; T <sub>sp</sub> ≤ 112 °C; <u>Fig. 1</u>		-	0.6	А
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>sp</sub> ≤ 112 °C; <u>Fig. 2</u> ; <u>Fig. 3</u>		-	1	А
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms; Fig. 4; Fig. 5		-	10	A
		half sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 8.3 ms		-	11	А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; SIN		-	0.5	A²s
dl <sub>T</sub> /dt	rate of rise of on-state current	I <sub>G</sub> = 400 μA		-	100	A/µs
I <sub>GM</sub>	peak gate current			-	1	А
V <sub>RGM</sub>	peak reverse gate voltage			-	5	V
P <sub>GM</sub>	peak gate power			-	1.2	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period		-	0.12	W
T <sub>stg</sub>	storage temperature			-40	150	°C
T <sub>j</sub>	junction temperature		[2]	-	125	°C

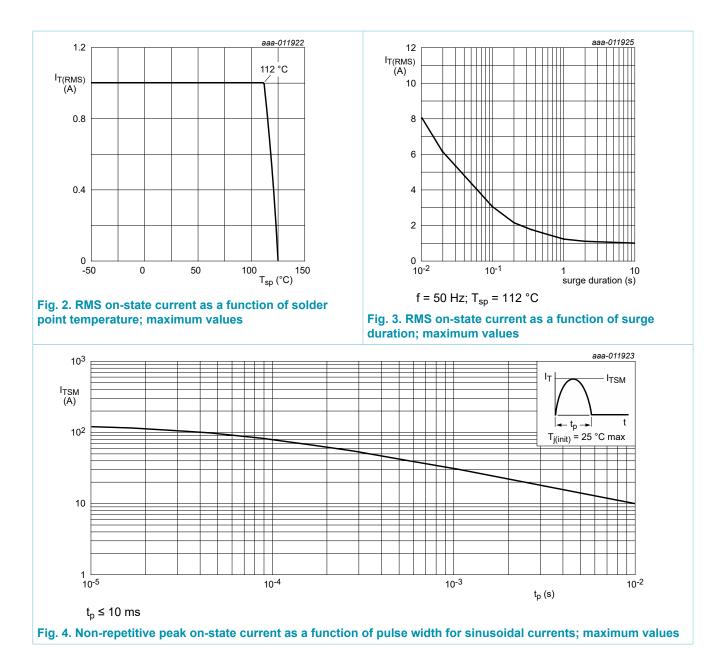
[1] Although not recommended, off-state voltages up to 800 V may be applied without damage, but the thyristor may switch to the onstate.

[2] Operation above 110°C may require the use of a gate to cathode resistor of  $1k\Omega$  or less.



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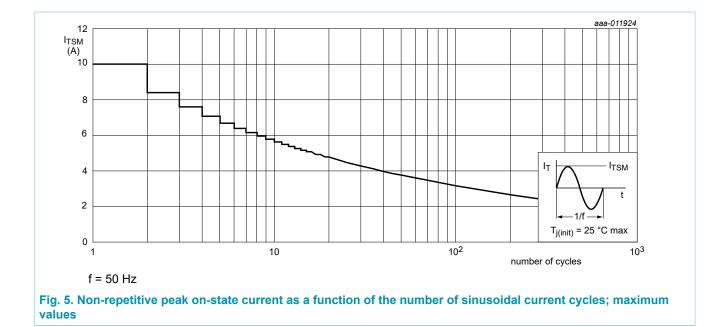
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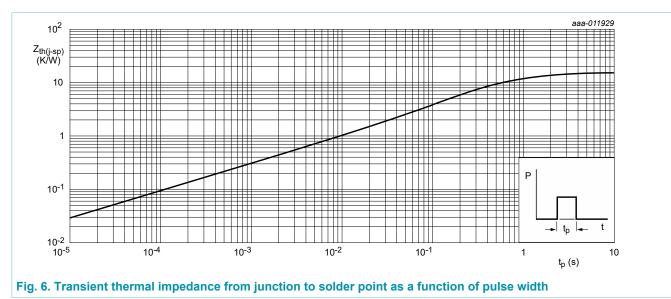
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## 8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point	<u>Fig. 6</u>	-	-	15	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air	printed circuit board mounted; pad area; Fig. 7	-	70	-	K/W
		printed circuit board mounted; minimum footprint; Fig. 8	-	156	-	K/W

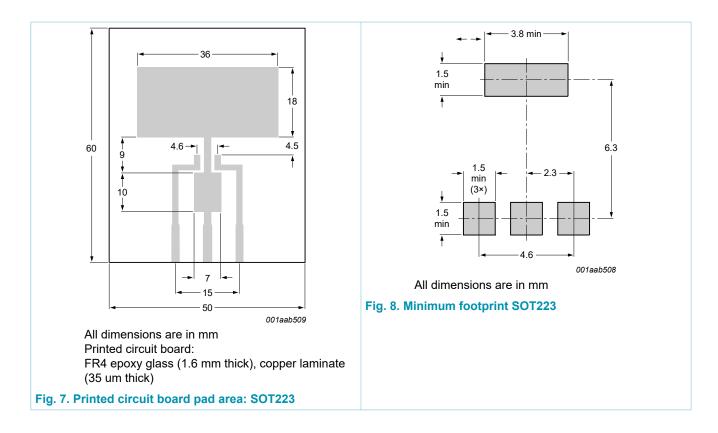


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## 9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara				- 31-		
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>i</sub> = 25 °C; <u>Fig. 9</u>	-	50	200	μA
IL	latching current	$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T}_j = 25 \text{ °C};$ Fig. 10	-	0.17	10	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 11</u>	-	0.1	6	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 2 A; T <sub>j</sub> = 25 °C; <u>Fig. 12</u>	-	1.3	1.5	V
V <sub>GT</sub>	gate trigger voltage	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; Fig. 13	-	0.4	1	V
		$V_D$ = 600 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 125 °C; Fig. 13	0.1	0.2	-	V
I <sub>D</sub>	off-state current	V <sub>D</sub> = 600 V; T <sub>j</sub> = 125 °C	-	0.1	0.5	mA
I <sub>R</sub>	reverse current	V <sub>R</sub> = 600 V; T <sub>j</sub> = 125 °C	-	0.1	0.5	mA
Dynamic ch	naracteristics	· · · · ·				
dV <sub>D</sub> /dt	rate of rise of off-state voltage		-	50	-	V/µs
t <sub>gt</sub>	gate-controlled turn-on time	$I_{TM}$ = 4 A; V <sub>D</sub> = 600 V; I <sub>G</sub> = 5 mA; dI <sub>G</sub> / dt = 0.2 A/µs; T <sub>j</sub> = 25 °C	-	2	-	μs
t <sub>q</sub>	commutated turn-off time	$V_{DM} = 402 \text{ V}; \text{ T}_{j} = 125 \text{ °C}; \text{ I}_{TM} = 4 \text{ A};$ $V_{R} = 35 \text{ V}; (dI_{T}/dt)_{M} = 30 \text{ A}/\mu\text{s}; dV_{D}/$ $dt = 2 \text{ V}/\mu\text{s}; \text{ R}_{GK(ext)} = 1 \text{ k}\Omega; (V_{DM} = 67\% \text{ of } V_{DRM})$	-	100	-	μs

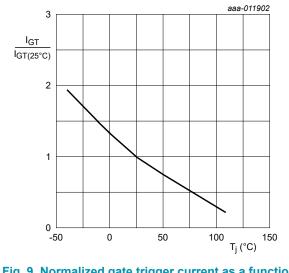
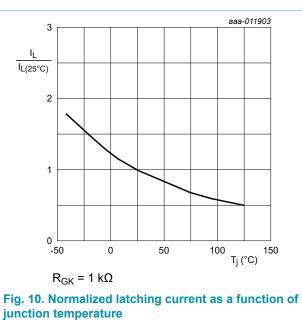
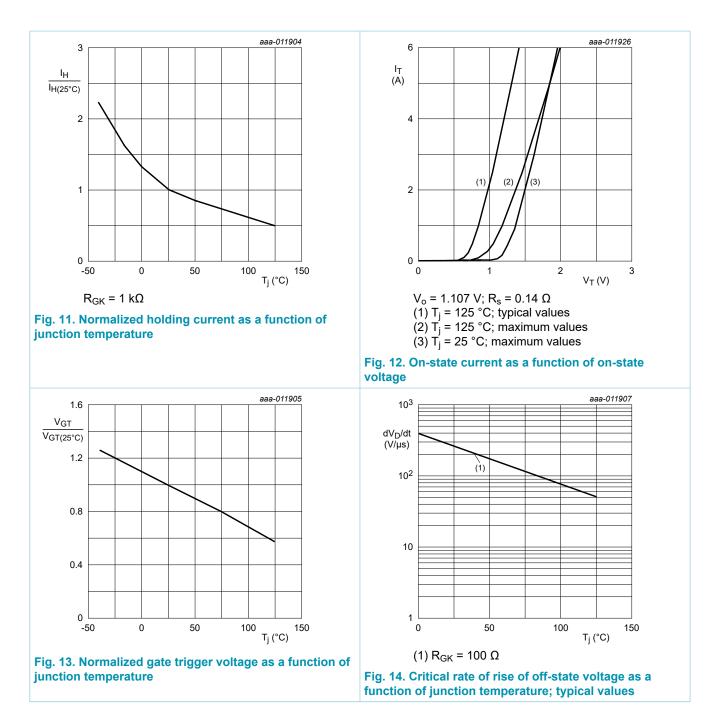


Fig. 9. Normalized gate trigger current as a function of junction temperature



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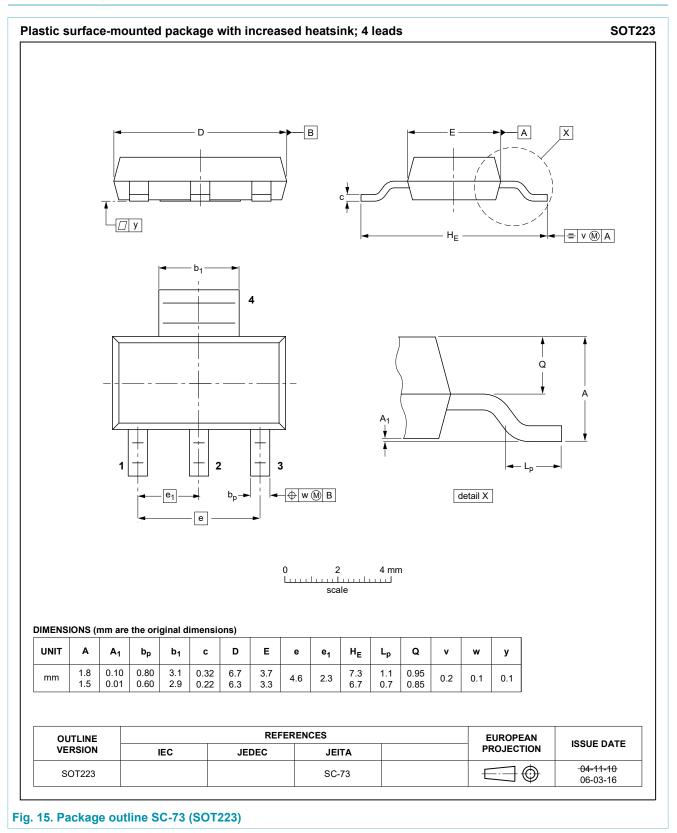
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## **10. Package outline**



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## 11. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [ <u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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